

Erratum: Temporal and spatial evolution of Si atoms in plasmas produced by a nanosecond laser ablating silicon carbide crystals [Phys. Rev. E **80, 016405 (2009)]**

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(Received 2 April 2010; published 21 April 2010)

DOI: [10.1103/PhysRevE.81.049907](https://doi.org/10.1103/PhysRevE.81.049907)

PACS number(s): 52.38.Mf, 52.70.-m, 99.10.Cd

In this paper, there is an error in Fig. 4: the lower two panels were switched and mislabeled. The corrected version of Fig. 4 is given below.

The figure caption and all main text reference to the figure are correct and were not changed. The error does not affect the conclusions of the paper. The authors regret this error.

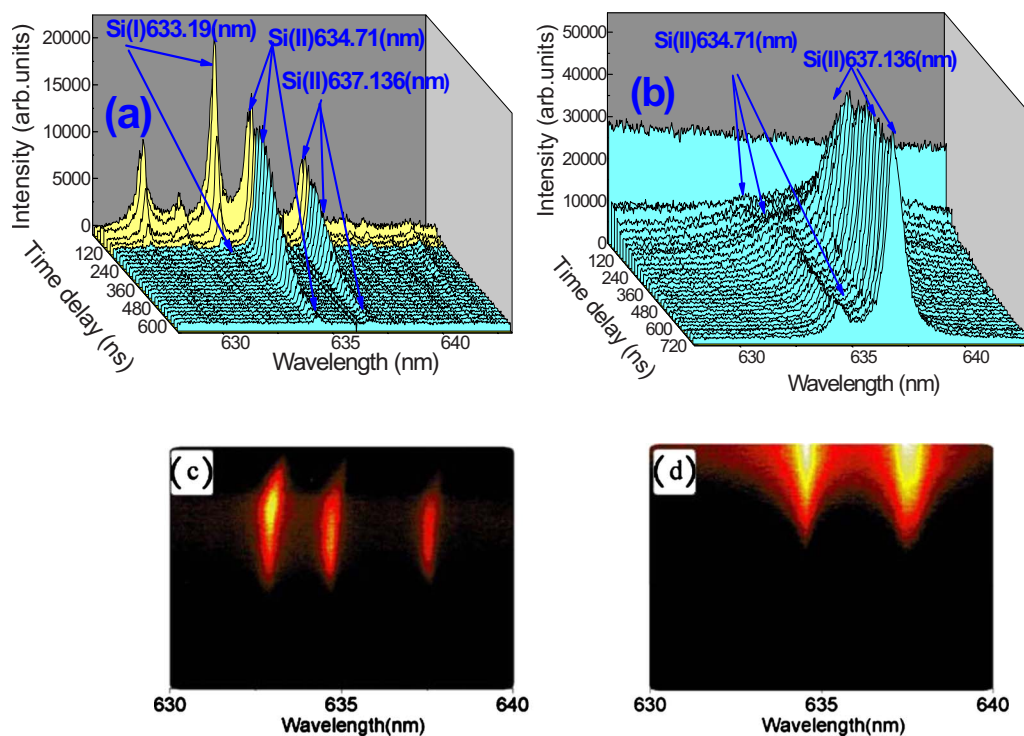


FIG. 4. (Color online) The intensity of the emission spectra from Si atoms and ions versus delay time (gate width of 5 ns), measured at 2 mm from the target surface, (a) measured in vacuum, and (b) measured in air. The images of the emission from Si atoms and ions at delay time of 80 ns recorded in vacuum (c), and in air (d), respectively.